

Important notice

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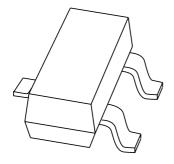
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



PMBD354 Schottky barrier double diode

Product data sheet Supersedes data of 2002 Aug 06 2003 Mar 25



NXP Semiconductors Product data sheet

Schottky barrier double diode

PMBD354

FEATURES

- · Low forward voltage
- Small SMD package
- Low capacitance
- · Matched capacitance.

APPLICATIONS

- UHF mixer
- Sampling circuits
- Modulators
- · Phase detection.

DESCRIPTION

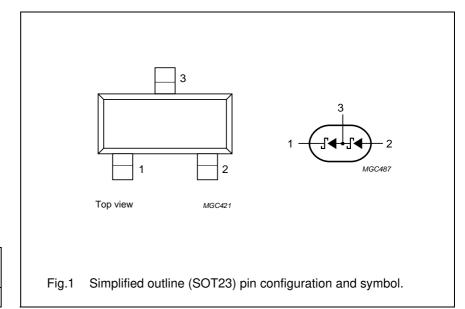
Planar Schottky barrier double diode in a SOT23 small plastic SMD package.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾	
PMBD354	*V8	

PINNING

PIN	DESCRIPTION	
1	cathode k ₁	
2	anode a ₂	
3	common connection a ₁ , k ₂	



Note

- 1. * = p: Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Per diode	Per diode			
V _R	continuous reverse voltage	_	4	٧
I _F	continuous forward current	_	30	mA
T _{stg}	storage temperature	-65	+150	°C
T _j	junction temperature	_	100	°C

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NXP Semiconductors Product data sheet

Schottky barrier double diode

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT		
Per diode	Per diode					
V _F	forward voltage	see Fig.2				
		I _F = 0.1 mA	350	mV		
		I _F = 1 mA	450	mV		
		I _F = 10 mA	600	mV		
I _R	reverse current $V_R = 3 V$; note 1; see Fig.3 0.25 μA		μΑ			
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.4	1	pF		
ΔC_d	capacitance matching	$f = 1 \text{ MHz}; V_R = 0$ 0.1 pF				

Note

1. Pulse test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

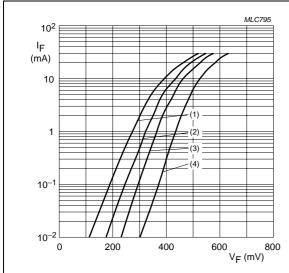
1. Refer to SOT23 standard mounting conditions.

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Schottky barrier double diode

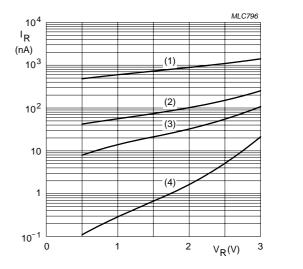
PMBD354

GRAPHICAL DATA



- (1) $T_{amb} = 100 \, ^{\circ}C$.
- (2) $T_{amb} = 60 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 100 \, ^{\circ}C$.
- (2) $T_{amb} = 60 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Reverse current as a function of reverse voltage; typical values.

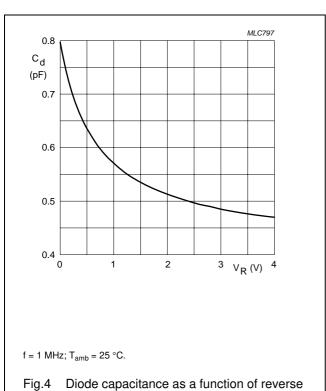


Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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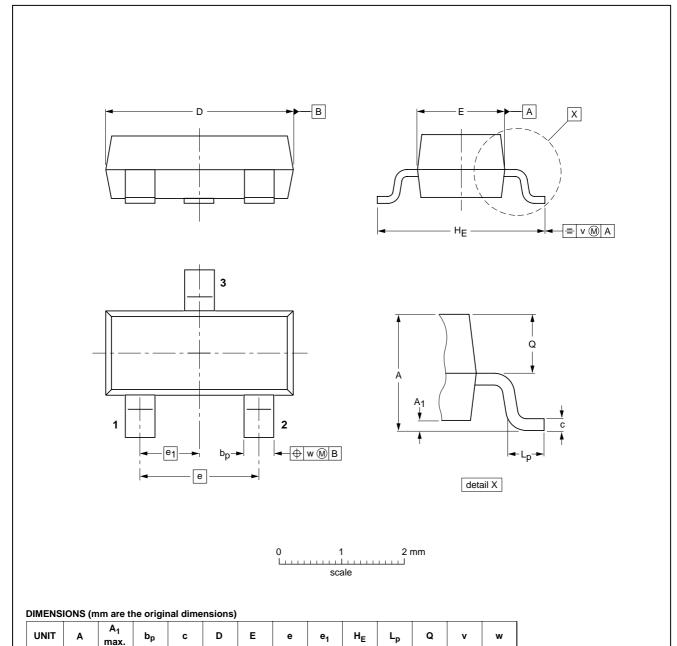
Schottky barrier double diode

PMBD354

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUL DATE
SOT23		TO-236AB				97-02-28 99-09-13

1.9

0.45

0.55

0.1

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max.

0.48

0.38

0.15

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Schottky barrier double diode

PMBD354

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

For additional information please visit: http://www.nxp.com

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